

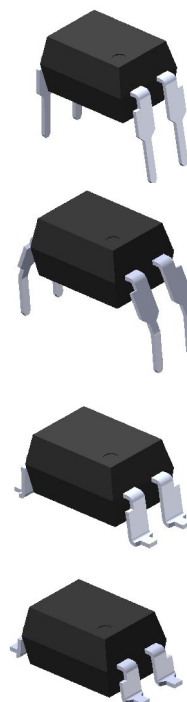
4PIN PHOTOTRANSISTOR PHOTOCOUPLER

Features

- Current transfer ratio
(CTR:MIN.50% at $I_F = 5\text{mA}$, $V_{CE} = 5\text{V}$)
High isolation voltage between input and output
($V_{iso} = 5000\text{ V rms}$)
- Compact dual-in-line package
FL817*:1-channel type
- Pb free

Options available

- Leads with 0.4"(10.16mm) spacing (M Type)
- Leads bends for surface mounting (S Type)
- Tape and Reel of Type I for SMD(Add"-TA" Suffix)
- Tape and Reel of Type II for SMD(Add"-TB" Suffix)
- The tape is 16mm and is wound on a 33cm reel



Applications

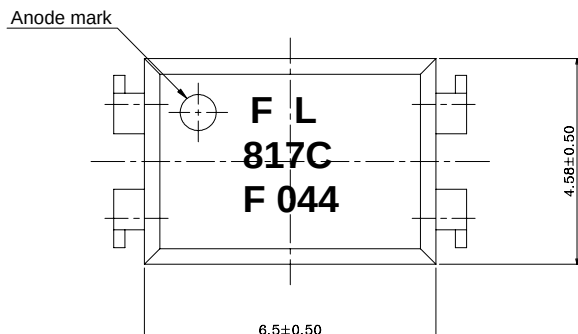
- Computer terminals
- System appliances, measuring instruments
- Registers, copiers, automatic vending machines
- Cassette type recorder
- Electric home appliances, such as fan heaters, etc.
- Signal transmission between circuits of different potentials and impedances

Device Selection Guide

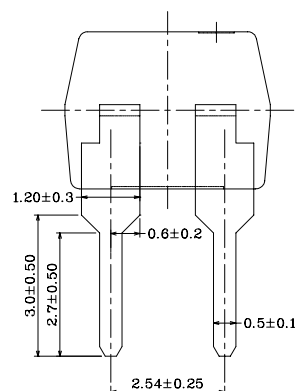
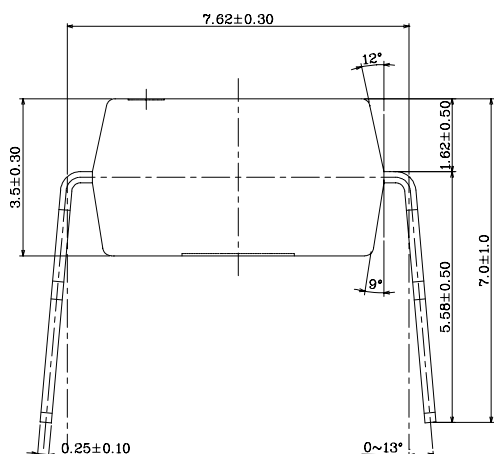
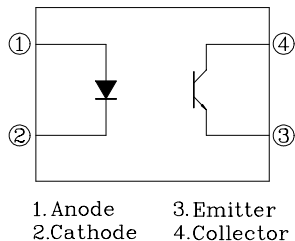
Part. No.	Chip Material	
	IR	PT
FL817*	GaAs	Silicon

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Package Dimensions

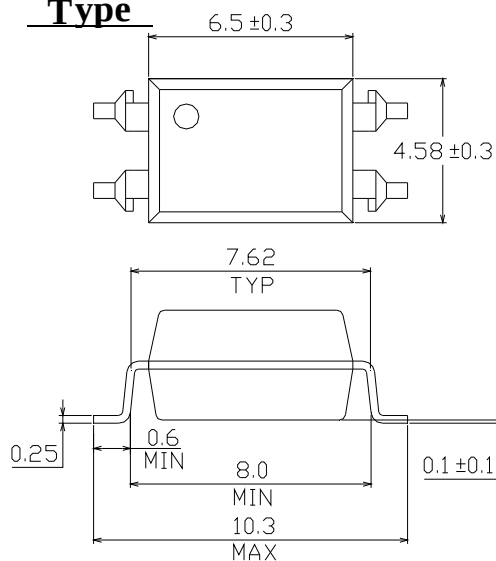


PIN NO. AND INTERNAL CONNECTION DIAGRAM



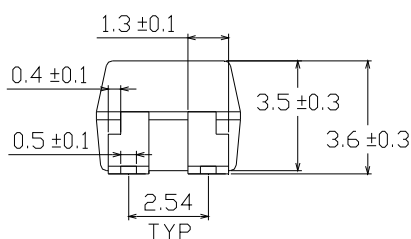
Package Dimensions

Type

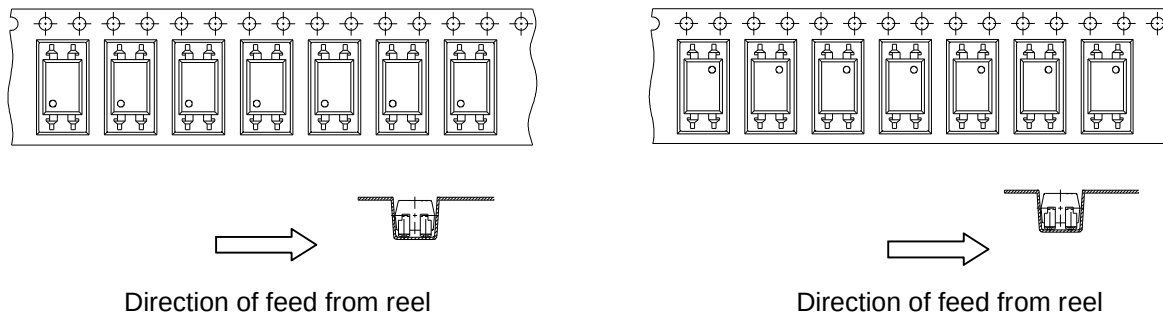


Notes:

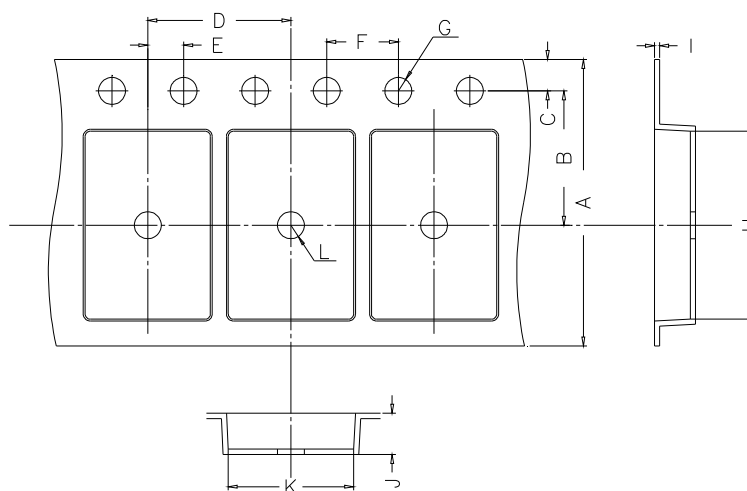
1. Rank shall be or shall not be marked
2. Year date code
3. 2-digit work week
4. All dimensions are in millimeters
5. Specifications are subject to change without notice



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Tape Dimensions



Dimension No.	A	B	C	D	E	F
Dimension(mm)	16.00±0.3	7.5±0.1	1.75±0.1	8.0±0.1	2.0±0.1	4.0±0.1
Dimension No.	G	H	I	J	K	L
Dimension(mm)	1.5±0.1/-0	10.4±0.1	0.4±0.05	4.55±0.1	5.1±0.1	1.5±0.05

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Absolute Maximum Ratings(Ta=25°C)

Parameter		Symbol	Rating	Unit
Input	Forward Current	I_F	50	mA
	Reverse Voltage	V_R	6	V
	Power Dissipation	P	70	mW
Output	Collector Power Dissipation	P_C	150	mW
	Collector Current	I_C	50	mA
	Collector-Emitter Voltage	V_{CEO}	70	V
	Emitter-Collector Voltage	V_{ECO}	6	V
Total Power Dissipation		P_{tot}	200	mW
*1 Isolation Voltage		Viso	5000	V rms
Operating Temperature		Topr	-55~+110	°C
Storage Temperature		Tstg	-55~+125	°C
*2 Soldering Temperature		Tsol	260	°C

*1 AC for 1 minute, R.H= 40~ 60%RH

-Isolation voltage shall be measured using the following method.

- (1) Short between anode and cathode on the primary side and between collector, emitter and base on the secondary side.
- (2) The isolation voltage tester with zero-cross circuit shall be used.
- (3) The waveform of applied voltage shall be a sine wave

*2 For 10 seconds

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Electro-Optical Characteristics(Ta=25°C)

Parameter		Symbol	Min.	Typ.	Max.	Unit	Condition
Input	Forward	V_F	-	1.2	1.4	V	$I_F=20\text{mA}$
	Reverse Current	I_R	-	-	10	μA	$V_R=4\text{V}$
	Terminal	C_t	-	30	250	pF	$V=0, f=1\text{kHz}$
Output	Collector Dark current	I_{CEO}	-	-	100	nA	$V_{CE}=20\text{V}$
	Collector-Emitter breakdown voltage	BV_{CEO}	70	100	-	V	$I_c=0.1\text{mA}$
Transfer Characteristics	Current Transfer ratio	CTR	50	-	600	%	$I_F=5\text{mA}, V_{CE}=5\text{V}$
	Collector-Emitter saturation voltage	$V_{CE(sat)}$	-	0.1	0.2	V	$I_F=20\text{mA}, I_c=1\text{mA}$
	Isolation resistance	R_{ISO}	5×10^{10}	10^{11}	-	Ω	DC500V, 40~60%R.H
	Floating capacitance	C_f	-	0.6	1.0	pF	$V=0, f=1\text{MHz}$
	Cut-off frequency	f_c	-	80	-	kHz	$V_{CE}=5\text{V}, I_c=2\text{mA}$ $R_L=100\Omega, -3\text{dB}$
	Rise time	t_r	-	4	18	μs	$V_{CE}=2\text{V}$ $I_c=2\text{mA}, R_L=100\Omega$
	Fall time	t_f	-	3	18	μs	

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Supplement

Current Transfer Ratio CTR

Sub-Model No.	Rank mark	CTR (%)	Condition
FL817 (A)	A	80 to 160	$I_F = 5 \text{ mA}$ $V_{CE} = 5 \text{ V}$ $T_a = 25^\circ\text{C}$
FL817 (B)	B	130 to 260	
FL817 (C)	C	200 to 400	
FL817 (D)	D	300 to 600	

Fig. 1 Forward Current vs.
Ambient Temperature

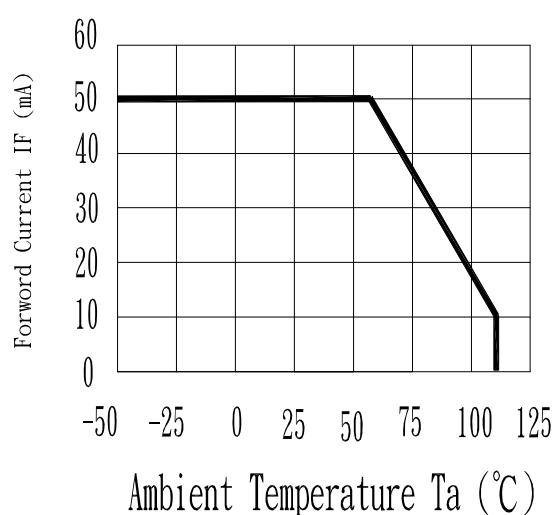
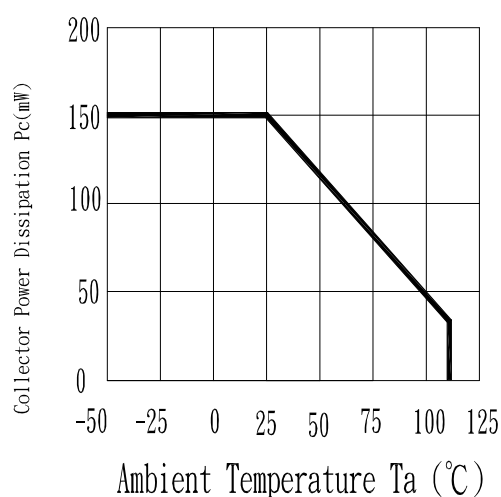


Fig.2 Collector Power Dissipation vs.
Ambient Temperature



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Fig. 3 Collector-emitter Saturation Voltage vs. Forward Current (Ta=25°C)

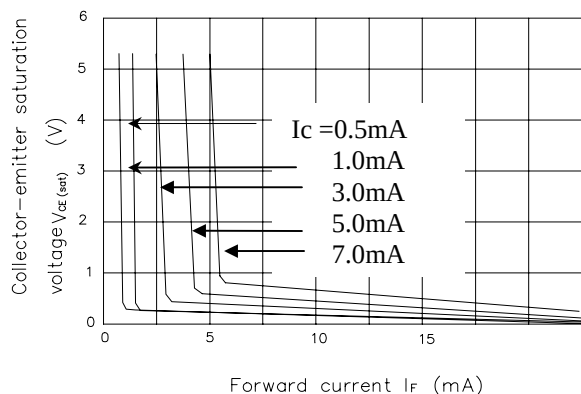


Fig. 4 Current transfer Ratio vs. Forward Current

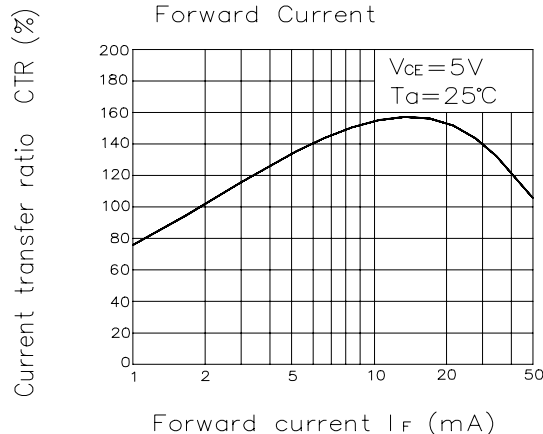


Fig. 5 Forward Current vs. Forward Voltage

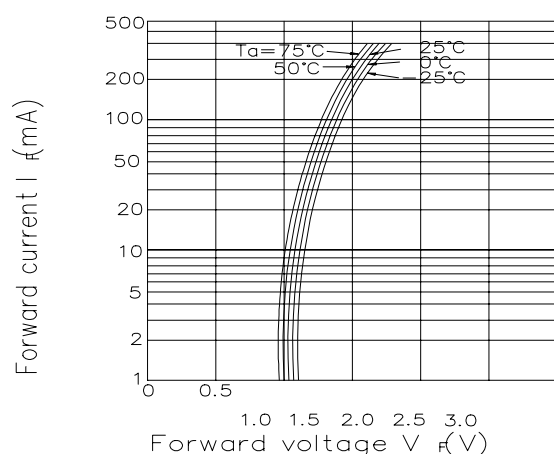


Fig. 6 Collector Current vs. Collector-emitter Voltage (Ta=25°C)

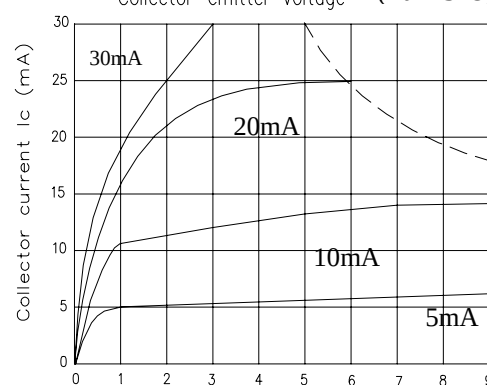


Fig. 8 Collector-emitter Saturation Voltage vs. Ambient Temperature

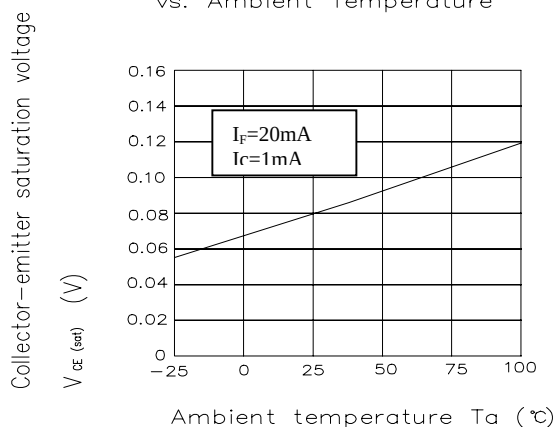
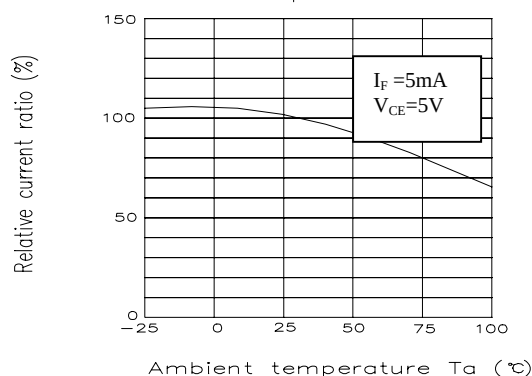


Fig. 7 Relative Current Transfer Ratio vs. Ambient Temperature



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Fig.9

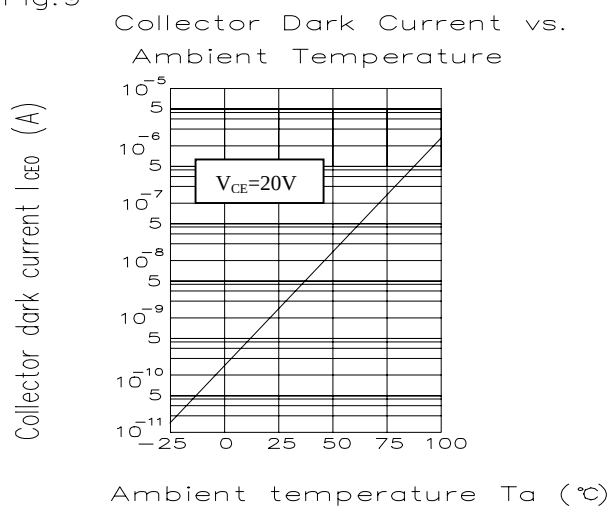


Fig.10

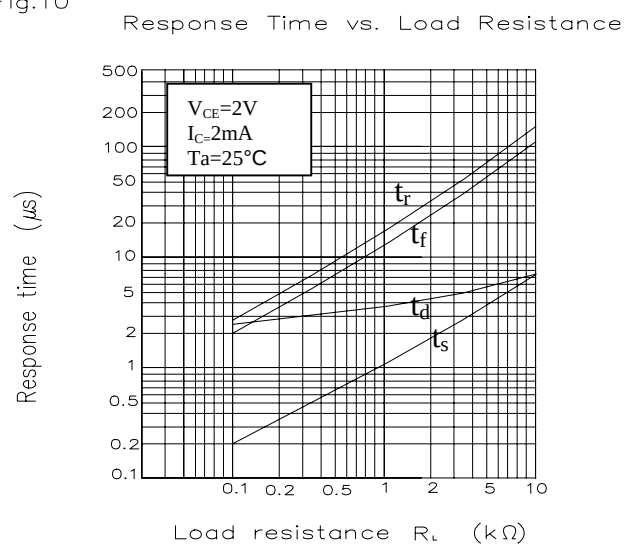
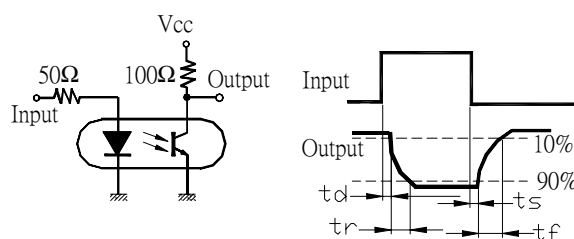
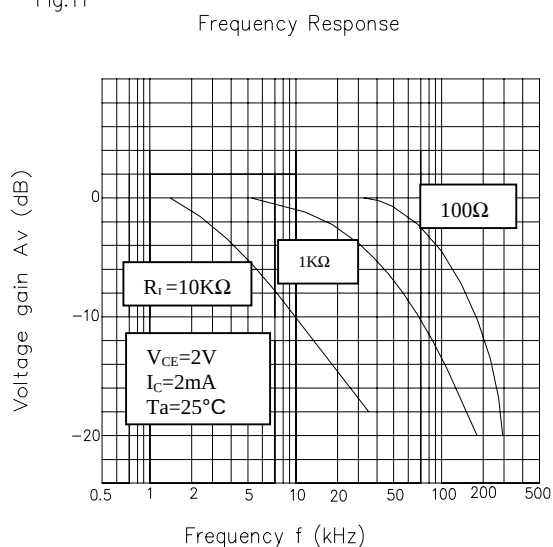


Fig.11



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RELIABILITY PLAN

- The reliability of products shall be satisfied with items listed below.

Confidence level : 90 % , LTPD : 10 %

Classification	Test Item	Description & Condition	(Acc.) Sample	Failure Criteria	Reference Standard
Endurance Test	Operation Life *	Ta = 25 ± 3°C IR: If = 50 mA Pt: Pc = 130 mW (Vf=1.4v) , 1000 hrs	0 / 22	CTR shift > 1.2 Vf > U* 1.0 Ir > U * 1.0 Vce(sat) >U*1.0 Bvceo < L*1.0 Bveco < L*1.0 L :Low Spec.Limit U : Up Spec. Limit	MIL-S-750 : 1026 MIL-S-883 : 1005 JIS C 7021 : B-1
	High Temperature / High Humidity Reverse Bias (H3TRB)	Ta = 85 ± 3°C , Humi. = 85 % rh Pt: 80% * Vce (max rating) , 1000 hrs	0 / 22		JIS C 7021 : B-11
	High Temperature Reverse Bias (HTRB)	Ta = 105 ± 3°C Pt: 100% * Vce (Max rating) , 1000 hrs	0 / 22		JIS C 7021 : B-8
	Low Temperature Storage	Ta = -50 ± 3°C , 1000 hrs	0 / 22		JIS C 7021 : B-12
	High Temperature Storage	Ta = 125 ± 3°C , 1000 hrs	0 / 22		JIS C 7021 : B-10 MIL-S-883 : 1008
	Auto clamp	P = 15 PSIG , Ta = 121 °C , Humi. = 100 % rh , 48 hrs	0 / 22		JESD 22-A102-B
Environmental Test	Temperature Cycling (Air to Air)	125°C ~ - 55 °C 30 ~ 30 min , 100 cycles	0 / 22		MIL-S-883 :1010 JIS C 7021 : A-4
	Thermal Shock (Liquid to Liquid)	125 ~ - 55°C t (dwell) = 5 min t (trans.) = 10 sec , 100 cycles	0 / 22		MIL-S-202 : 107D MIL-S-750 : 1051 MIL-S-883 :1011
	Solder Resistance	Ta = 260 ± 3°C t (dwell) = 10 ± 1 sec	0 / 22		MIL-S-750 : 2031 JIS C 7021 : A-1
	Solder Ability	Ta = 230 ± 3 °C t (dwell) = 5 ± 1 sec	0 / 22		MIL-S-883 : 2003 JIS C 7021 : A-2

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